

## Electronic Supplementary Information

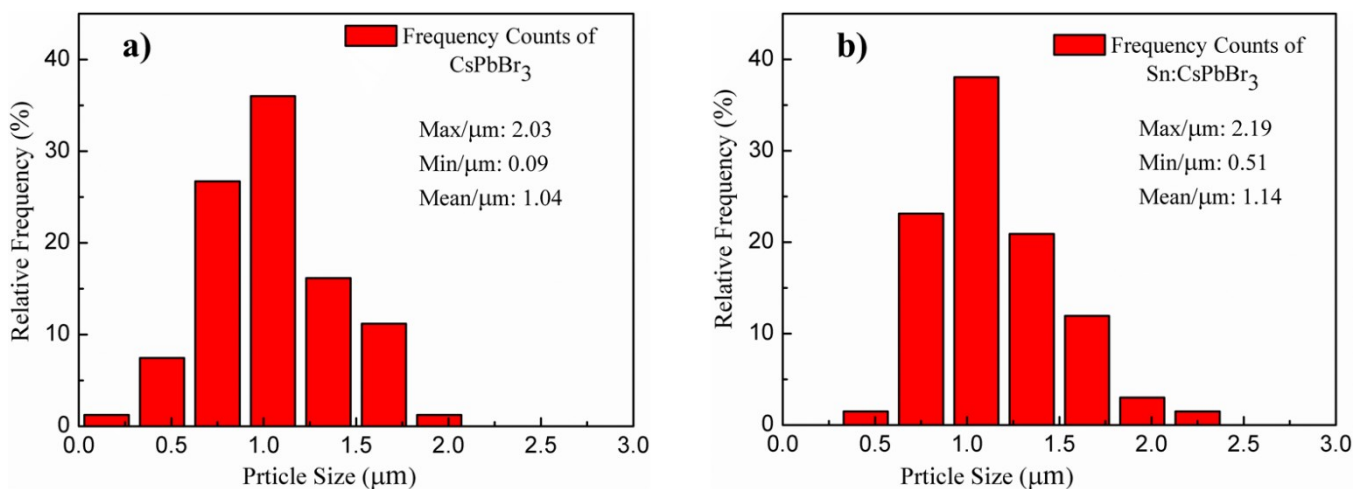
### Direct deposition of Sn doped CsPbBr<sub>3</sub> perovskite for efficient solar cells application

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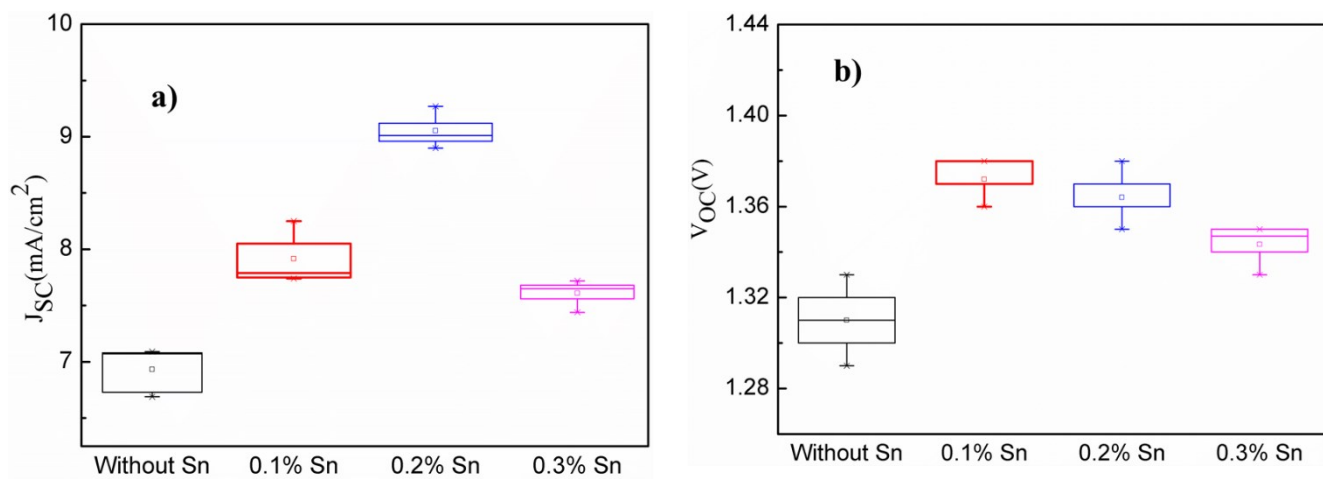
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**Figure S1.** The static particle size distribution data of (a) pristine CsPbBr<sub>3</sub> and (b) with 0.2 % Sn ion doped CsPbBr<sub>3</sub> perovskite thin-film.



**Figure S2.** (a) Current density ( $J_{sc}$ ) and (b) open-circuit voltage ( $V_{oc}$ ) statistical distribution of without Sn, 0.1% Sn, 0.2% Sn and 0.3% Sn CsPbBr<sub>3</sub> PSCs devices respectively.